Spin-Orbit M ediated Control of Spin Qubits

Christian Flindt,^{1,2} Anders S. S rensen,¹ and Karsten Flensberg¹

¹Niels Bohr Institute, Universitetsparken 5, DK-2100 Copenhagen, Denmark ²M IC { Department of M icro and Nanotechnology, NanoD TU, Technical University of Denmark, Building 345east, DK-2800 Kongens Lyngby, Denmark (D ated: M arch 23, 2022)

We propose to use the spin-orbit interaction as a means to control electron spins in quantum dots, enabling both single qubit and two qubit operations. Very fast single qubit operations may be achieved by tem porarily displacing the electrons. For two qubit operations the coupling mechanism is based on a combination of the spin-orbit coupling and the mutual long-ranged C oulomb interaction. C om pared to existing schemes using the exchange coupling, the spin-orbit induced coupling is less sensitive to random electrical uctuations in the electrodes de ning the quantum dots.

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It is believed that solid state systems could facilitate large-scale quantum computing [1] due to the welldeveloped fabrication techniques that allow for a high degree of scalability. On the other hand, solid state system s are inherently more noisy than, e.g., quantum optical system s, and in particular several sources of low -frequency noise are typically present in a solid state environment. O ne prom inent candidate for solid state quantum com puting uses electron spins in sem iconductor quantum dots as carriers of the fundam ental unit of inform ation, the qubit [2]. Electron spins have the advantage that they are weakly coupled to the surroundings and therefore weakly sensitive to noise. At the same time, however, this weak coupling makes the electron spin hard to control experimentally. To couple two spin qubits, it was proposed to use the exchange coupling between electron spins in neighboring quantum dots [3], and this was recently dem onstrated experim entally [4]. Here the triplet and singlet spin states have di erent charge pro-

les, thereby enabling electrical control of the coupling. Unfortunately, this spin-charge coupling also makes the qubits sensitive to electrical noise and in particular to low-frequency noise [5]. In this setting the spin-orbit interaction is also considered as a source of decoherence [6], because it m ixes spin and charge. Recently, how ever, it has been proposed that it could also play a role in the coherent interaction of qubits [7]. In this Letter we take these ideas further and propose to use the spin-orbit interaction as a general means to manipulate electron spins. The spin-orbit interaction allows for electrical control of both single and two qubit operations, but unlike the exchange interaction, the spin-orbit interaction generates dressed states of spin and charge where the mixing happens at a high frequency, making the interaction less susceptible to low-frequency noise.

W hile the general methods we propose in this Letter are applicable in a wide range of situations, we only consider a simplied one-dimensional model where the electrons are localized in quantum dots by an external potentialV (x). Physically, we may think of a structure like

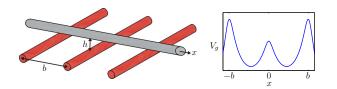


FIG.1: (Color online) A nanow ire (light gray) placed above three electrodes. The electrodes are used to de ne electrostatically a double quantum dot within the nanow ire. The electrodes are placed at a distance b apart, while the nanow ire is situated at a distance h above the plane of the electrodes. The inset shows a representative curve for the potential $V_g(x)$ along the nanow ire (the x-axis) with the electrodes placed at positions x = b, 0, b, respectively. The shown setup resen – bles the one used in the experiment in R ef. [8].

the one shown schem atically in Fig.1 which was recently realized experimentally [8], and we give realistic parameters corresponding to such a system. In our model we include a perpendicular magnetic eld B (de ning the z direction) and a spin-orbit coupling of the form p^Y, where p denotes the momentum in the x direction [15]. W ith two electrons trapped in a double dot potential the H am iltonian of the system reads

$$H = H_{1} + H_{2} + \frac{e^{2}}{4 "_{r} "_{0} j x_{2} x_{1} j'}$$

$$H_{i} = \frac{p_{i}^{2}}{2m} + V (x_{i}) + \frac{1}{2} g_{B} B_{i}^{z} + p_{i} j'; \quad i = 1;2:$$
(1)

Here denotes the strength of the spin-orbit coupling, while m is the e ective electron mass. Below, we rst consider how the spin-orbit interaction allows us to control the spin state of a single electron and then move on to discuss how the combination of the spin-orbit interaction and the C oulom b interaction enables two qubit operations in a manner analogous to the method used for trapped ions [9].

First, we consider a single electron, and for our analytical calculation we assume that the potential is harmonic, but has a time varying equilibrium position denoted x (t), V (x) = m ! $_0^2$ (x x(t) $\hat{Y}=2$. We have om itted the subscript i, since we are considering a single electron. Physically the time varying equilibrium position can be induced with time varying potentials on the electrodes. We proceed by performing a unitary transform ation H ! UHU^y with U = exp (i ^y (x x(0))='_{so}), where we have introduced the spin-orbit length '_{so} = ~=m , which characterizes the length scale of the spin-orbit interaction, i.e., in the absence of a magnetic eld, a spin along the x or z directions is ipped after traveling a distance '_{so}=2. W ith this transform ation the H am iltonian becomes

$$H = \frac{p^{2}}{2m} + \frac{1}{2}m !_{0}^{2} (x - x(t))^{2} + \frac{1}{2}g_{B}B$$

$$\cos \frac{2(x - x(0))}{s} = \sin \frac{2(x - x(0))}{s} + \frac{1}{2}g_{B}B$$
(2)

We further assume that the renorm alized Zeem an splitting $_z$ $g_B B$ (g de ned below) is much smaller than the oscillator energy ~!_0, and that the equilibrium position is changed adiabatically with respect to the oscillator frequency !_0 (1=`_o) (dx (t)=dt), where `_o = _______ ~=m !_0 is the characteristic oscillator length. In this limit, we can trace out the motional degrees of freedom and obtain

$$H_{spin} = \frac{1}{2}g_{B}B \cos \frac{2(x(t) - x(0))}{s_{so}} z$$

$$\sin \frac{2(x(t) - x(0))}{s_{so}} z$$
(3)

with the renorm alized g-factor [10] given by

$$g = g e^{2i(x + x(0)) = '_{so}} = g exp ('_{o} = '_{so})^{2} : (4)$$

The renormalization of the q-factor relects that the qubits states are not pure states of the electron spin, but dressed states of spin and position [11]. Normally, such admixture of spin and position introduces decoherence because the position is coupled to charge uctuations, but in this case the charge distribution is independent of the spin state, and produces no decoherence in the absence of a magnetic eld. W ith a magnetic eld the dressed states are still insensitive to slow ly varying electric elds (slow compared to the Zeem an frequency $_{z}$ =~), which only shift the equilibrium position, while the spin state follows adiabatically. The dressed states will, how ever, be sensitive to slow ly varying gradients of the electric elds which change the trap frequency $!_0$. Because of the dependence of g on $'_{\circ}$ in Eq. (4) such uctuations in ! 0 will a ect the Zeem an splitting and thereby cause decoherence of the spin states. A swe shall see below this is one of the major lim itations for the coupling of two qubits, but it will not signi cantly a ect the fast single qubit operations, provided that the ground state width is reasonably well-de ned.

Remarkably, the coupling of spin and position can be used to perform single qubit operations if one applies an electric eld with a su ciently fast variation in time. If we consider the Ham iltonian in Eq. (3) there are two distinct principles for such single qubit operations. One was considered in Ref. [12], where sm all am plitude oscillations of the equilibrium position $(j \times (t)j \quad s_{\infty})$ at the Zeem an frequency produced spin-orbit induced electron spin resonance (ESR) oscillations between the two spin states. The second possibility, sim ilar to Ram sey spectroscopy, for producing spin reversals is to rst perform a large rapid change of the equilibrium position for a very short duration. In particular, if we change x(t)by $s_{\infty}=4$ on a time scale much shorter than $s_{\infty} = s_{\infty}$, the e ective Ham iltonian becomes $H_{spin} = s_{\infty} = s_{\infty}$. Consequently, after a time $s_{\infty} = s_{\infty}$ the spin state has been

ipped and we can then change x (t) back to the original position. The second procedure has the advantage that it does not rely on any resonance conditions and allows for very rapid m anipulation of the spin. Since the time scale can be changed by changing the magnetic eld, the spin ip time will in practice only be limited by how fast one can change the voltage on the electrodes. As a particular exam ple of m aterial param eters, we take param eters typical for InAs, i.e., $m = 0.027 m_e$, $\sim = 3 10^8 m eV m$ and g = 14.8, giving $s_{\infty} = 94 \text{ nm}$. W ith B = 40 mTand $\sim !_{\,0}$ = 0:5 meV, we get $`_{o}$ = 75 nm, so that the Zeem an frequency is z = -2 (2)4:4 GHz. The required displacem ent of the electron spin can be achieved by applying an electric eld $E = \sum_{so}^{n} \frac{2}{s} = 4e = 6.6 \text{ V/nm}$, which for a setup like in Fig. 1 with an electrode spacing of b = 500 nm corresponds to a voltage of roughly 3 mV, and the entire spin ip process can be achieved in approxim ately 0.1 ns.

In addition to being important for performing logical operations in a quantum computer, the ability to perform rapid spin ips also allows the reduction of the leading kinds of decoherence due to the presence of magnetic impurities and the hyper ne coupling to nuclear spins. For electron spins in G aAs a dephasing time on the order of 10 ns has been reported [4], and we expect a similar time scale for InAs. This dephasing can, however, be reversed by applying pulses, which ip the spin on a much shorter time scale [4].

The spin-orbit interaction can also mediate two-qubit interactions in a very elective way. Returning to the setup shown in Fig. 1 described by the Hamiltonian in Eq. (1), we consider next the possibility of using the dipole moment associated with displacements of the electron charges to couple the two spins. In this one dimensional geometry the two dots holding each one spin are separated by a distance $d = x_2$ $x_1 > 0$. We consider the limit where the two electrons are well-separated, allowing us to expand the C oulomb interaction term as $1=jx_2$ x_jj' 1=d $=d^2 + \ ^2=d^3$, while using d $(x_2 \ x_2)$ $(x_1 \ x_1)$. The rst term in this expansion

 $(x_2 \quad x_2) \quad (x_1 \quad x_1)$. The rst term in this expansion gives a constant contribution to the energy, the second term corresponds to constant forces, which rede ne the two equilibrium positions. The last term has diagonal term s, x_1^2 , which provide a small renormalization of the trapping frequencies. Finally, the interesting term is the cross-term $2(x_1 \quad x_1)(x_2 \quad x_2)=d^3$, which results in a coupling of the two orbitals degrees of freedom, and hence also, via the spin-orbit interaction, between the two spin degrees of freedom.

To calculate this coupling we go back to Eq. (2) (for each electron) with time independent equilibrium positions $x_i(t) = x_i(0)$, and perform perturbation theory in the magnetic eld. To second order in B the electrice H am iltonian for a single electron spin is still given by Eq. (3), i.e., $H_i = g_B B_i^z = 2$ (for i = 1;2) plus a spin independent contribution. The cross-term that couples the two spins gives rise to an electrice spin coupling term given by

$$H_{spin;12} = \frac{e^2}{2 "_0 "_r d^3} hx_1 x_1 ihx_2 x_2 i;$$
 (5)

where the brackets only refer to a trace over the vibrational state, not the spin state. Because the two orbital degrees to this order are decoupled the expectation value separates. To leading order in B, the displacement of the electrons can be found from Eq. (2) by rst order perturbation theory, and we obtain

$$h\mathbf{x}_{i} \quad \mathbf{x}_{i} \mathbf{i} = \begin{array}{c} \mathbf{x} \frac{\mathbf{g} \quad \mathbf{B} \quad \mathbf{B} \quad \mathbf{0}^{2}}{\mathbf{2} \quad \mathbf{0} \quad \mathbf{x}_{o}} \mathbf{i} \\ \mathbf{x}_{i} \mathbf{1} \quad \mathbf{x}_{i} \mathbf{1} = \begin{array}{c} \mathbf{x} \frac{\mathbf{g} \quad \mathbf{B} \quad \mathbf{B} \quad \mathbf{0}^{2}}{\mathbf{2} \quad \mathbf{0} \quad \mathbf{x}_{o}} \mathbf{i} \end{array}$$
(6)

C om bining this with the single particle contributions, we arrive at the nale ective H am iltonian for the two spins

$$H_{spin} = \frac{x}{1} \frac{x}{2} + \frac{1}{2} g_{B} B \left(\frac{z}{1} + \frac{z}{2} \right); \quad (7)$$

where the coupling constant is given by

$$= \frac{e^2}{4 \, "_0 "_r} \frac{2 \, {}_0^4 \, (g_{BB} B)^2}{{}_{\infty}^2 \, (\sim !_0)^2 d^3} \, (8)$$

W e stress that this e ective H am iltonian is correct to all orders in the spin-orbit coupling, but only to second order in the B - eld and rst order in the C oulom b interaction between the two electrons. The last approximation can, how ever, be relaxed without changing the form of the H am iltonian, but at the expense of a more complicated expression for .

To characterize the stability of the proposed coupling mechanism to slow ly varying perturbations, such as uctuations in the gate electrodes, we develop a more realistic model for the double-dot potential V (x). We are having in m ind an experimental setup like the one shown in Fig. 1 [8], and consequently we consider the electrostatic potential V_g (x) created by three parallel electrodes with spacing b, each modeled as an in nite line charge, along the x-axis running perpendicular to the electrodes at a distance h above the plane of the electrodes. The

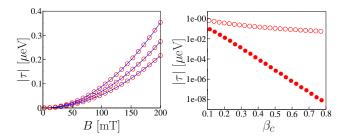


FIG. 2: (Color online) Numerical calculation of the coupling . Material parameters correspond to InAs and we use \sim !g = 1 meV, 1 = 1, xg = 53 nm, h = 0.5xg, b = 10xg. Left panel: The coupling as function of applied magnetic eld B for c = 0.6 (upper circles), 0.7, 0.8 (lower circles). Solid lines show Eq. (8) with the orbital energy spacing \sim ! extracted from the low-energy spectrum and d being the only tting-parameter. Corresponding to c = 0.6;0:7;0.8, we have \sim ! = 0:39;0:40;0:42 m eV, and d = 8:3xg;8:7xg;9:1xg, respectively. R ight panel: Open circles show the coupling as a function of the applied voltage on the central electrode parametrized by c with B = 40 m T. Solid circles show the contribution from the bare exchange coupling J.

ratio of the charge density on the left (central) electrode $_{1(c)}$ and the right electrode $_{r}$ is denoted $_{1(c)}$, i.e., $_{1(c)}$ $_{1(c)}=$ r, which we assume can be controlled via the voltages applied to the electrodes. Moreover, we de ne ~! $_{g}$ e $_{r}=4$ " $_{r}$ " and x_{g} ~=m ! $_{g}$, in terms of which we express the electrostatic potential as

$$V_{g}(x) = V_{e}(x + b; 1) + V_{e}(x; c) + V_{e}(x - b; 1)$$
 (9)

with $V_e(x;) = -!_g \ln (x^2 + h^2) = x_g^2$. A representative curve for $V_g(x)$ is shown the inset of Fig. 1.

We have im plem ented num erically on a nite-size realspace grid the two-particle Ham iltonian in Eq. (1) using $V_q(x)$ in Eq. (9) as the potential V (x). With 100 500 grid-points, the resulting m atrix represen-Ν tation of the H am iltonian is large (dimension 4N 2 4N 2), but sparse, allowing for computationally cheap calculations of the low-energy spectrum from which we can extract the coupling of the various spin states. In the left panel of Fig. 2 we show num erical calculations of the coupling as a function of applied B - eld. The renormalized Zeeman splitting due to the applied B-eld is much smaller than the spacing of the orbital levels, and we thus expect Eq. (8) to hold. The num erical results show excellent agreem ent with the analytic expression. For the parameters used in the gure typical interaction strengths are = (2) f, with f 0.1 GHz, corresponding to gate times on the order of 1=(2f)5 ns.

In the right panel of F ig. 2 we show num erical results for the coupling as a function of the voltage applied to the central electrode param etrized by $_{\rm c}$. In order to determ ine the contribution arising from the bare exchange coupling (due to the Pauli principle and the C oulom b interaction), we also show num erical results for the splitting of the spin states without the spin-orbit coupling.

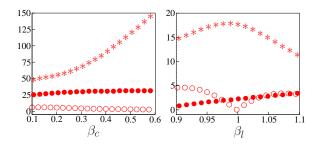


FIG.3: (C olor on line) Numerical calculations of the sensitivity of ity to uctuations in the gate electrodes. The sensitivity of the spin-orbit induced coupling and the Zeem an splitting z are quantied by $j(1=) (@ =@ _i) j i = c; 1$ (open circles) and $j(1=) (@ _z=@ _i) j i = c; 1$ (stars), respectively. M aterial parameters correspond to InAs. The other parameters are $B = 80 \text{ m T}, ~!_g = 1 \text{ m eV}, x_g = 53 \text{ nm}, h = 0.5x_g, and$ $b = 10x_g$. In both panels solid circles show the sensitivity of the bare exchange coupling $j(1=J) (@J=@ _i) j i = c; 1$. Left panel: Sensitivity to uctuations in the central electrode. The electrostatic potential is symmetric, i.e., $_1 = 1$. Right panel: Sensitivity to uctuations in the left electrode with $_c = 0.7$.

C om pared to the bare exchange coupling J, which is clearly exponentially dependent on the applied voltage, the spin-orbit induced coupling shows a weaker voltage dependence.

Fluctuations in the electrostatic environment cause uctuations of the orbital level splitting $\sim !_0$ and the distance d. Typically these uctuations have the form of 1=f-noise and concentrating on the dom inating low frequency component, we characterize in the following the sensitivity of the coupling to electrical uctuations using a purely static calculation by taking derivatives with respect to c and l. For the spin-orbit induced coupling given in Eq. (8), we have $j(1=)(0=0!_0)!_0j=$ $4j!_0=!_0j$ and j(1=)(0=0d) dj = 3j d=dj. In order to perform reliable two qubit operations, both of these quantities must be much smaller than unity, which for the uctuations imply $j!_0=!_0j$; jd=dj 0:1. In Fig. 3, we show $j(1=) (@ = @_i) jas a function of _i; i= c; l. The$ 1;i = c;l, coupling is stable for $j(1 =) (0 = 0_i)_{ij}$ implying j _ij< 0:1;i = l;c according to the num erical results. This does not impose any unrealistic requirements on the experimental setup. For comparison we also show $j(1=J)(0J=0_i)j = c; l \text{ for the exchange in-}$ teraction J, which for uctuations in _c is an order of m agnitude m ore sensitive.

As discussed previously electrical uctuations also cause uctuations of the renormalized Zeeman splitting, z. For z, we have $j(1=) (@ _z=@!_0) !_0 j = (4 "_r"_0 \sim m d^3!_0^3 = e^2 g_{BB}) j!_0 = !_0 j$. For InAs with d = 500 nm, $\sim !_0 = 0.3 \text{ meV}$, B = 80 mT, $j(1=) (@ _z=@!_0) !_0 j' 50 j!_0 = !_0 j$ implying the stricter condition $j!_0 = !_0 j$ 0.01. In Fig. 3, we show numerical results for $j(1=) (@ _z=@ _i) j$ as a function of $_i; i = c; l$. The results indicate that we must require $j_{ij} < 0.01; i = l; c$ for the renormalized Zeeman splitter.

ting to be stable. If this requirem ent cannot be met in experiments, the problem may be circum vented by encoding a single qubit in a singlet-triplet pair as recently discussed in Refs. [4, 13] or alternatively by combining the gate with fast spin-echo pulses in plemented by rapidly shifting the position of the electrons.

In conclusion, we have presented a spin-orbit induced m echanism for coherent control of spin qubits in quantum dots. The spin-orbit coupling allows for fast single qubit operations, and the two qubit operations are robust against electrical uctuations in the electrodes de ning the double dot. We emphasize that although some of the above conclusions have been m ade in connection with a speci c experim ental setup in m ind, they also hold at a m ore general level.

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